Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT2173N

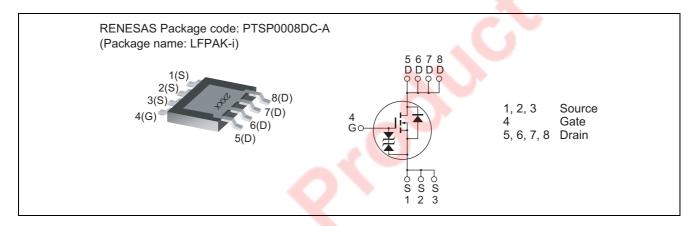
Silicon N Channel Power MOS FET Power Switching

REJ03G1684-0100 Rev.1.00 May 28, 2008

Features

- Capable of 8 V gate drive
- Low drive current
- High density mounting
- Low on-resistance $R_{DS(on)} = 12.3 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	100	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	25	Α
Drain peak current	I _{D(pulse)} Note1	100	Α
Body-drain diode reverse drain current	I _{DR}	25	Α
Avalanche current	I _{AP} Note 2	25	Α
Avalanche energy	E _{AR} Note 2	62.5	mJ
Channel dissipation	Pch Note3	30	W
Channel to case thermal resistance	θch-C	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. $Tc = 25^{\circ}C$

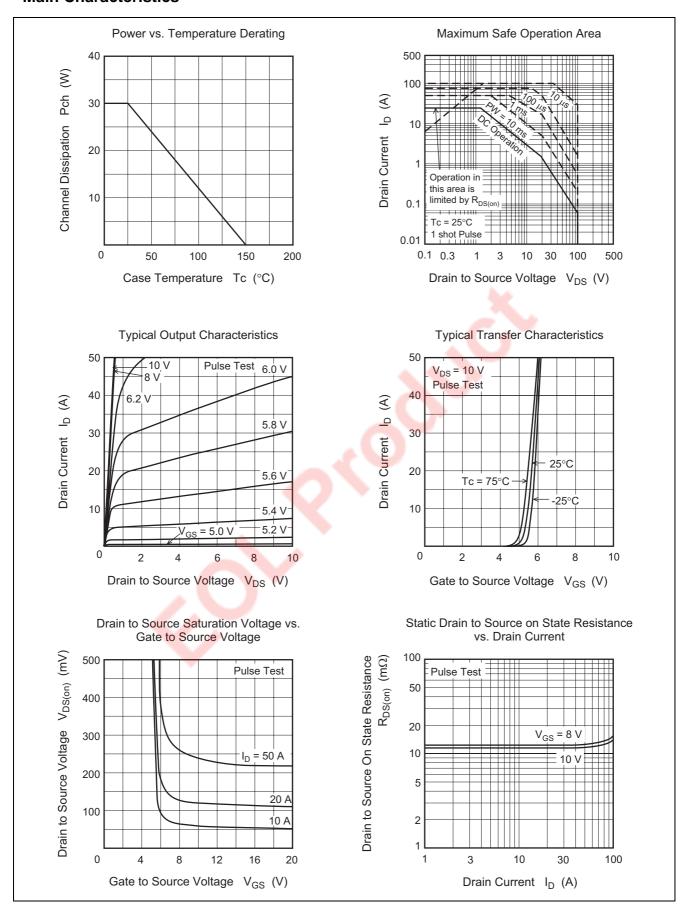
Electrical Characteristics

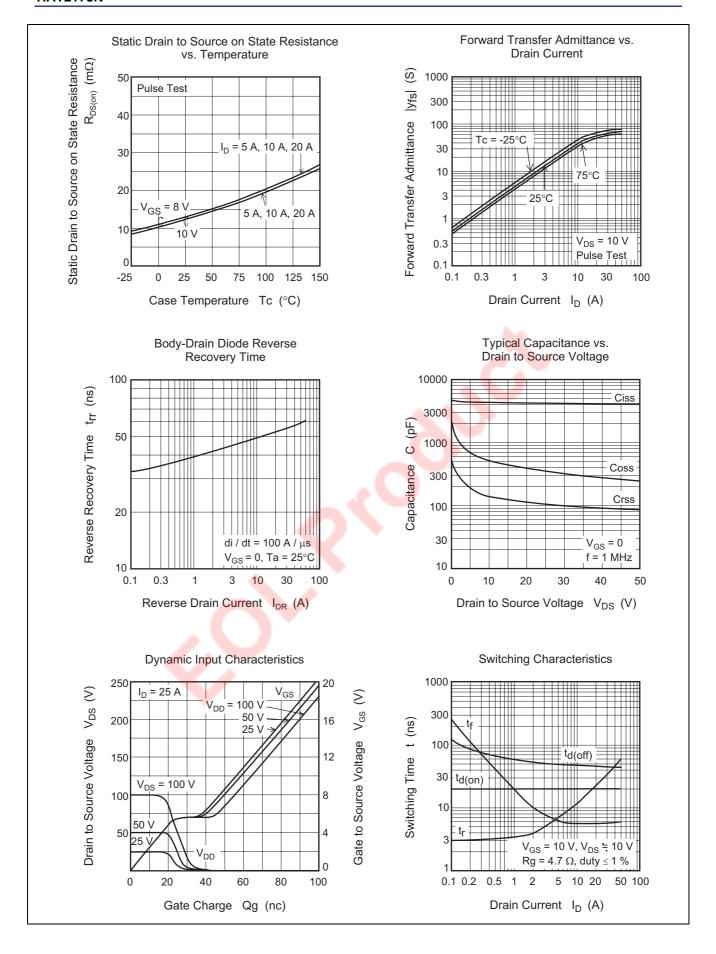
 $(Ta = 25^{\circ}C)$

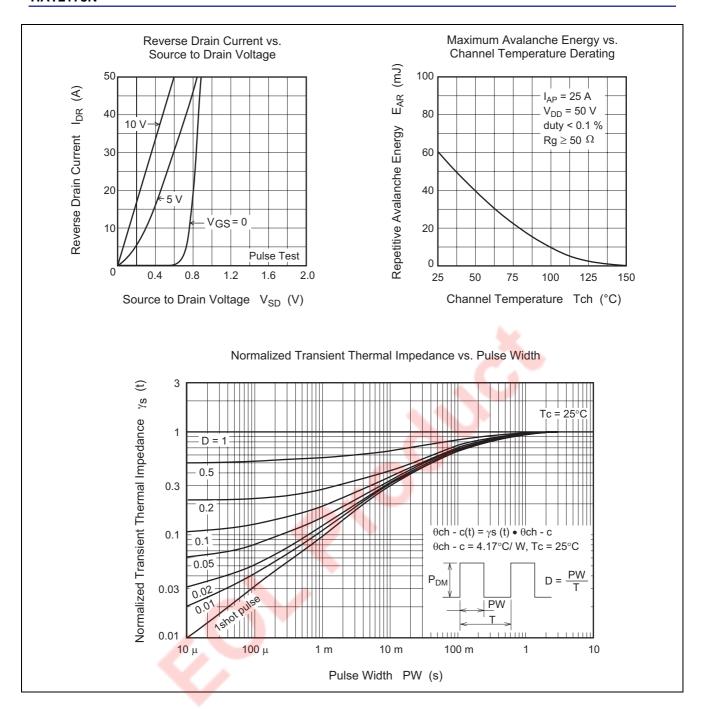
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100		_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20			V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_		±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_		1	μΑ	$V_{DS} = 40 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	4.0		6.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 20\text{mA}$
Static drain to source on state	R _{DS(on)}	_	12.3	15.3	$m\Omega$	$I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	13.3	17.8	$m\Omega$	$I_D = 12.5 \text{ A}, V_{GS} = 8 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	27	45		S	$I_D = 12.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	4350		pF	$V_{DS} = 10 \ V, V_{GS} = 0,$
Output capacitance	Coss	_	520	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	150		pF	
Gate resistance	Rg	_	0.5		Ω	
Total gate charge	Qg	_	61	_	nC	$V_{DD} = 50 \text{ V}, V_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	23	_	nC	$I_D = 25 A$
Gate to drain charge	Qgd	_	14.5	_	nC	
Turn-on delay time	t _{d(on)}	_	20	_	ns	$V_{GS} = 10 \text{ V}, I_D = 12.5 \text{ A},$
Rise time	t _r	_	15	_	ns	$V_{DD} \cong 30 \text{ V}, R_L = 2.4 \Omega,$
Turn-off delay time	t _{d(off)}	_	37	_	ns	$Rg = 4.7 \Omega$
Fall time	t _f	_	5.7		ns	
Body-drain diode forward voltage	V_{DF}		0.82	1.07	V	$I_F = 25 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t _{rr}		55		ns	$I_F = 25 \text{ A}, V_{GS} = 0$
time						di _F / dt = 100 A/ μs

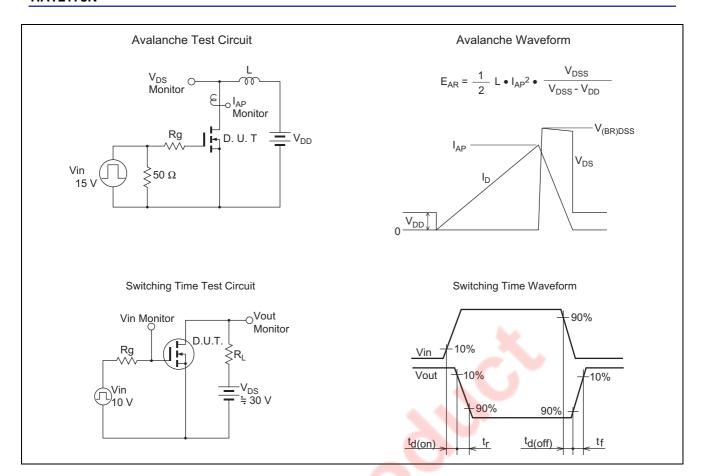
Notes: 4. Pulse test

Main Characteristics

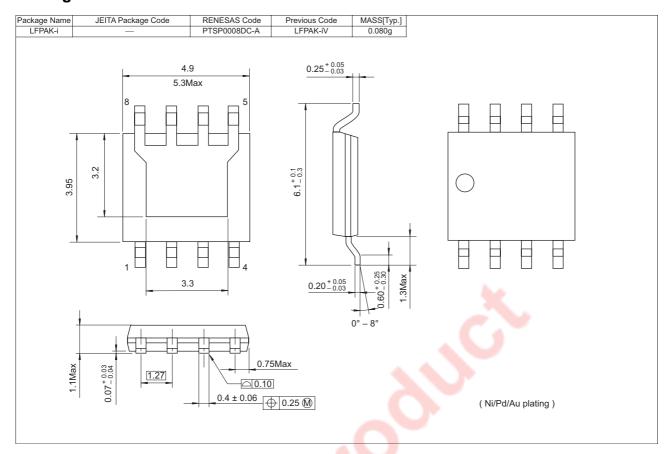








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2173N-EL-E	2500 pcs	Taping

Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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Renesas Technology America, Inc

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510